Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK1061

High Speed Switching Applications
Analog Switch Applications
Interface Applications

- Excellent switching times: ton = 14 ns (typ.)
- High forward transfer admittance: $|Y_{fs}| = 100 \text{ mS (min)}$
- Low on resistance: RDS (ON) = 0.6Ω (typ.)
- Enhancement-mode
- Complementary to 2SJ167

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DS}	60	V	
Gate-source voltage		V_{GSS}	±20	V	
Drain current	DC	I _D	200	mA	
	Pulse	I _{DP}	800		
Drain power dissipation (Ta = 25°C)		P _D	300	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Weight: 0.13 g (typ.)

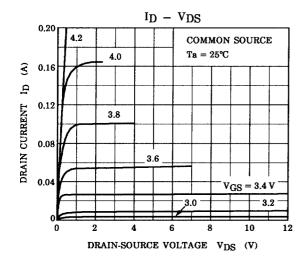


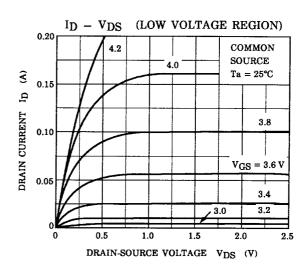
Electrical Characteristics (Ta = 25°C)

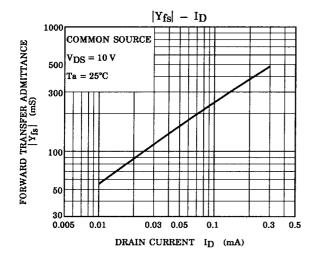
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA
Drain cut-off current		I _{DSS}	V _{DS} = 60 V, V _{GS} = 0	_	_	10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 1$ mA, $V_{GS} = 0$	60	_	_	V
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	2	_	3.5	V
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 50 mA	100	_	_	mS
Drain-source ON resistance		R _{DS (ON)}	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$	_	0.6	1.0	Ω
Drain-source ON voltage		V _{DS} (ON)	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$	_	30	50	mV
Input capacitance		C _{iss}		_	55	65	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	13	18	pF
Output capacitance		C _{oss}		_	40	50	pF
Switching time	Rise time	t _r	$\begin{array}{c c} 10 \text{ V} & \text{I}_{D} = 100 \text{ mA} \\ \hline V_{IN} & \text{O}_{OUT} \end{array}$	_	8	_	- ns
	Turn-on time	t _{on}	VDD =	_	14	_	
	Fall time	t _f	<i># #</i> 6 30 *	_	35	_	
	Turn-off Time	t _{off}	$\begin{aligned} &D.U. \leq 1\% \\ &V_{\text{IN}}: t_{\text{r}}, t_{\text{f}} < 5 \text{ ns} \\ &(Z_{\text{out}} = 50 \Omega) \end{aligned}$	_	75	_	

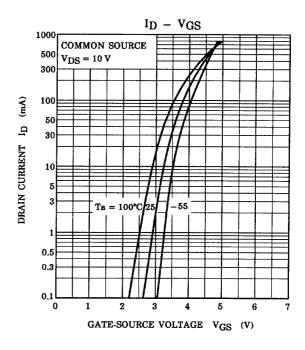
Note: This transistor is the electrostatic sensitive device. Please handle with caution.

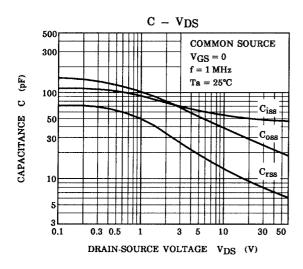
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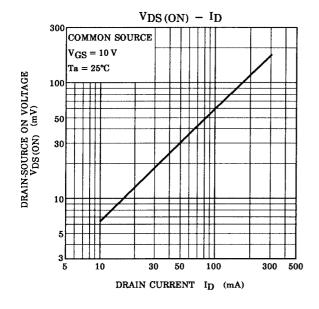


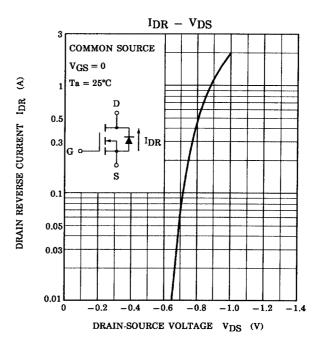


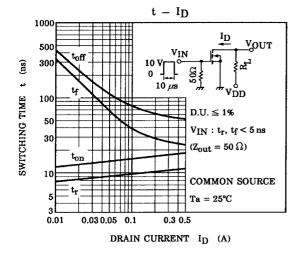


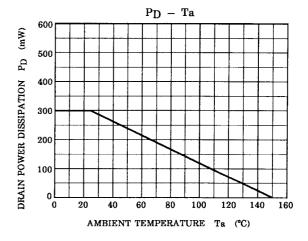


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